

A photograph of the dome of St. Peter's Basilica in Rome, Italy, under a clear blue sky. The dome is the central focus, with other smaller domes and architectural details visible in the background. The image is used as a background for the title slide.

電子回路論第8回

Electric Circuits for Physicists #8

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物性研究所
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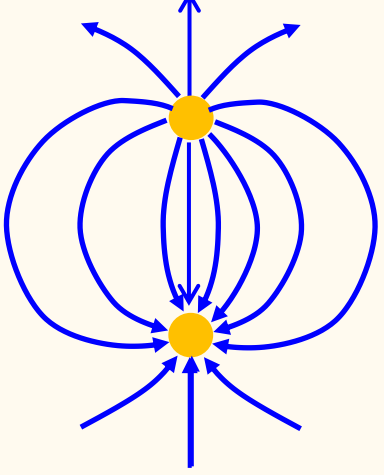
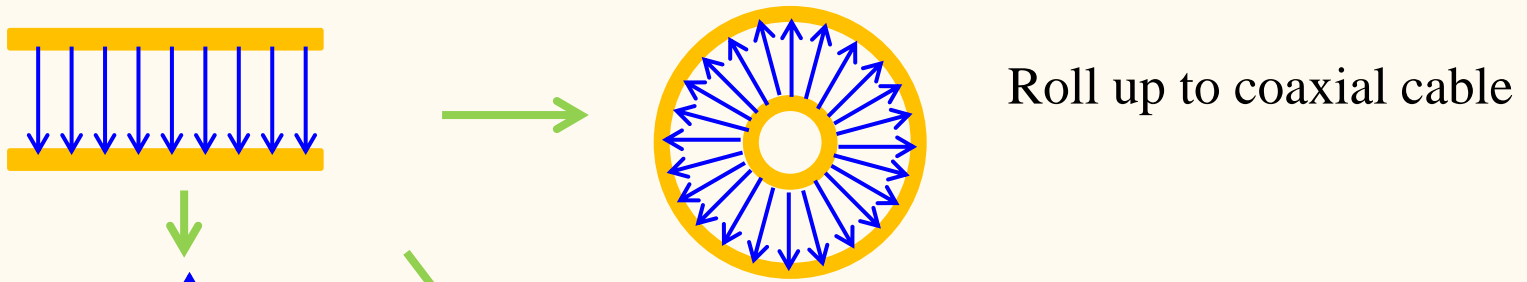
Shingo Katsumoto

Outline

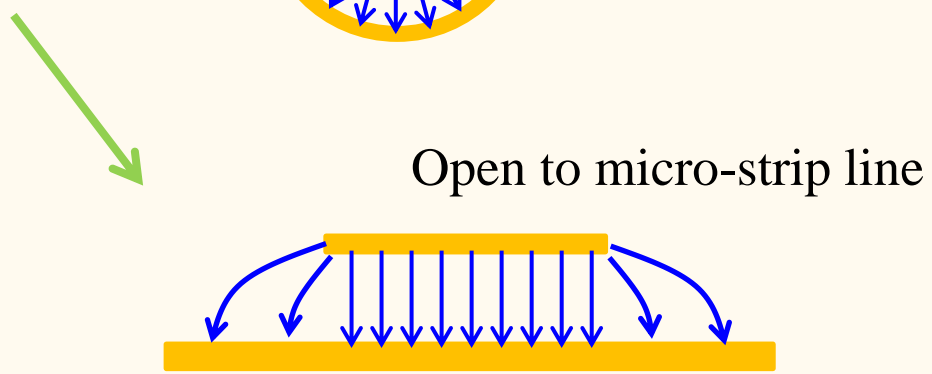
Various transmission lines
Termination and connection
Smith chart
S-matrix (S-parameters)

Transmission lines with TEM mode

Transmission lines with **two conductors** are “families”.
Electromagnetic field confinement with parallel-plate capacitor



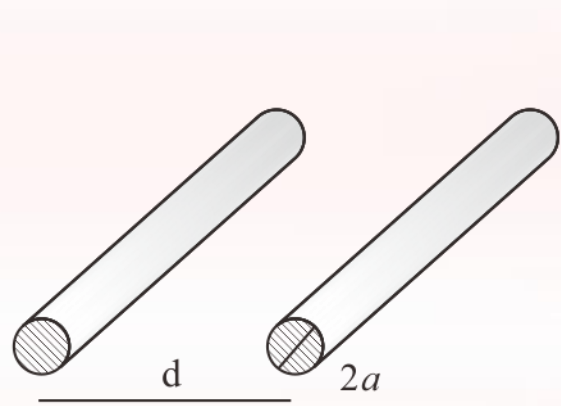
Shrink to dipole (Lecher line)



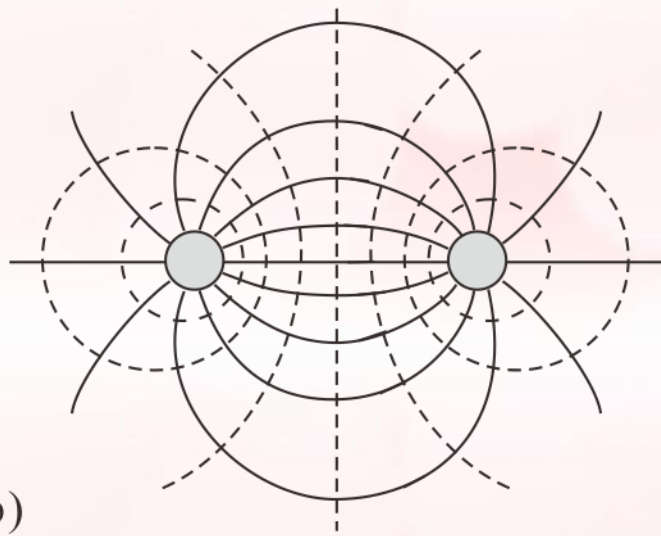
Commonly

TEM is the primary mode.

Lecher line



(a)



(b)

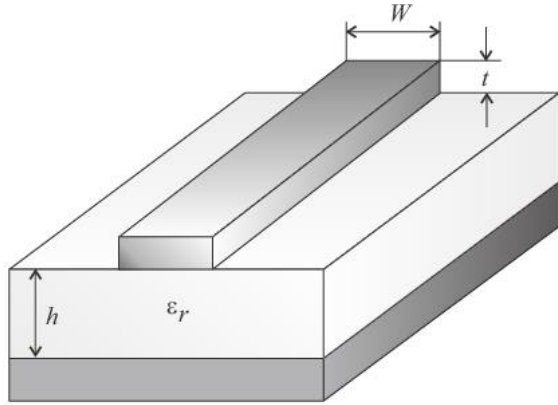


(c)

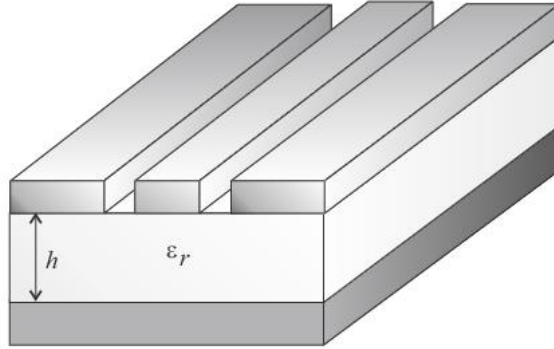
$$\phi_1 = -\phi_2 = \frac{J\sqrt{\mu}}{2\pi} \log \frac{d}{a}$$

$$Z_0 = \sqrt{\frac{\mu}{\epsilon}} \frac{1}{\pi} \log \frac{d}{a}$$

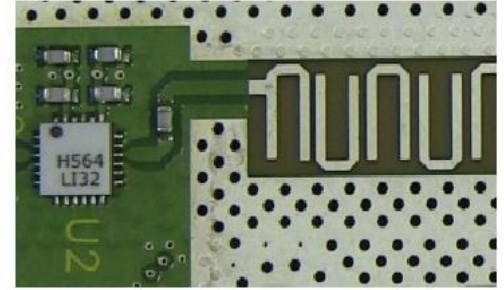
Micro strip line



(a)



(b)



(c)

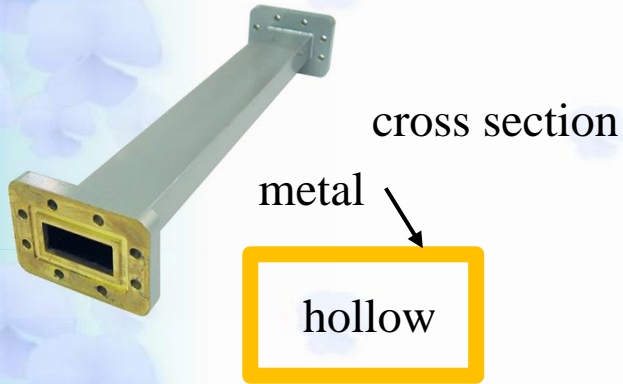
Wide ($W/h > 3.3$) strip

$$Z(W, h, \epsilon_r) = \frac{Z_{F0}}{2\sqrt{\epsilon_r}} \left\{ \frac{W}{2h} + \frac{1}{\pi} \log 4 + \frac{\epsilon_r + 1}{2\pi\epsilon_r} \log \left[\frac{\pi e}{2} \left(\frac{W}{2h} + 0.94 \right) \right] \frac{\epsilon_r - 1}{2\pi\epsilon_r^2} \log \frac{e\pi^2}{16} \right\}^{-1}$$

Narrow ($W/h < 3.3$) strip

$$Z(W, h, \epsilon_r) = \frac{Z_{F0}}{\pi\sqrt{2(\epsilon_r + 1)}} \left\{ \log \left[\frac{4h}{W} + \sqrt{\left(\frac{4h}{W} \right)^2 + 2} \right] - \frac{1}{2} \frac{\epsilon_r - 1}{\epsilon_r + 1} \left(\log \frac{\pi}{2} + \frac{1}{\epsilon_r} \log \frac{4}{\pi} \right) \right\}$$

Waveguide



Electromagnetic field is confined into a simply-connected space.



TEM mode cannot exist.

Maxwell equations give

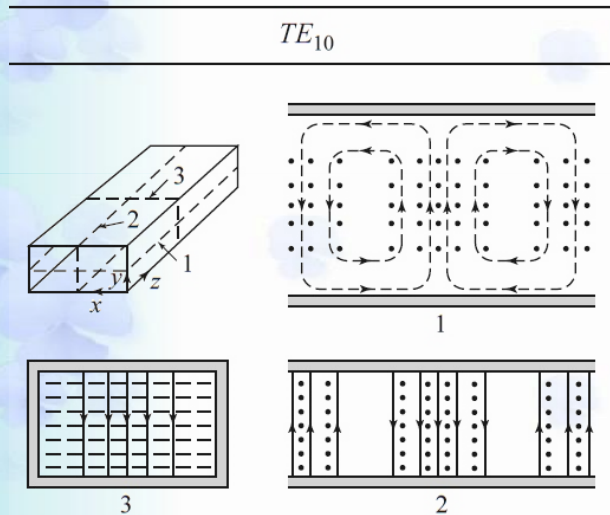
$$\left[\frac{\partial^2}{\partial x^2} + \frac{\partial^2}{\partial y^2} \right] E_z = -(\omega^2 \epsilon \mu + \gamma^2) E_z,$$

$$\left[\frac{\partial^2}{\partial x^2} + \frac{\partial^2}{\partial y^2} \right] H_z = -(\omega^2 \epsilon \mu + \gamma^2) H_z.$$

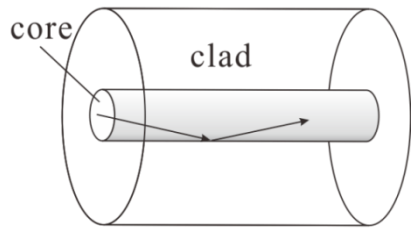
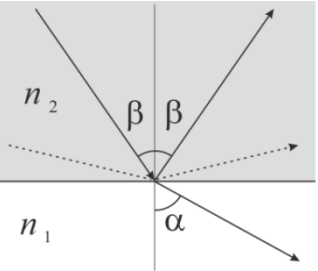
Helmholtz equation

$E_z = 0$: TE mode,

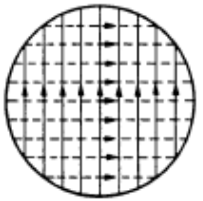
$H_z = 0$: TM mode



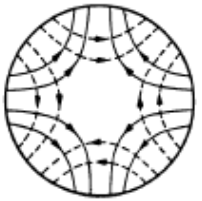
Optical fiber



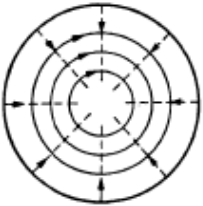
Difference in dielectric constant
step-type optical fiber



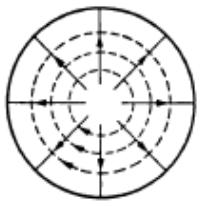
HE₁₁



HE₂₁

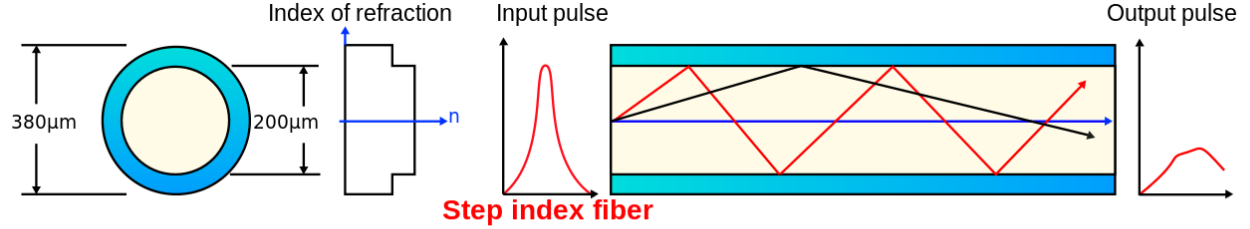


TE₀₁

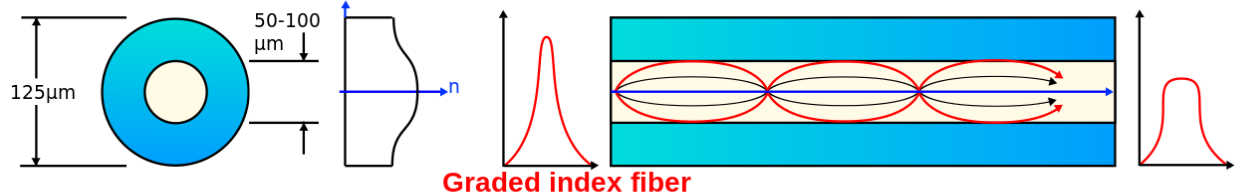


TM₀₁

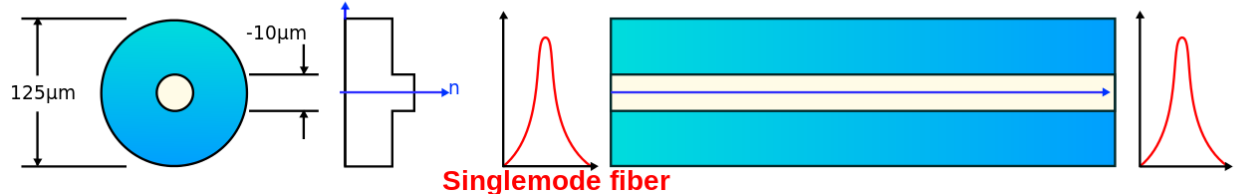
no dispersion



Step index fiber

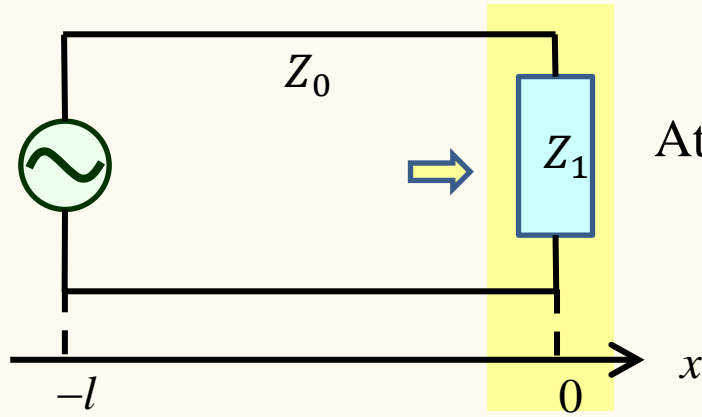


Graded index fiber



Singlemode fiber

Connection and termination



At $x = 0$:

$$J = \underbrace{J_+}_{\text{progressive}} + \underbrace{J_-}_{\text{retrograde}} \quad (\text{definition right positive})$$

$$V = V_+ + V_- = Z_0(J_+ - J_-)$$

$$Z_1 = \frac{V}{J} = \frac{J_+ - J_-}{J_+ + J_-} Z_0$$

Termination of a transmission line with length l and characteristic impedance Z_0 at $x = 0$ with a resistor Z_1 .

Reflection coefficient is $r = \frac{V_-}{V_+} = -\frac{J_-}{J_+} = \frac{Z_1 - Z_0}{Z_1 + Z_0}$

Comment: Sign of Ohm's law in transmission lines reflects direction of waves (depends on the definitions).

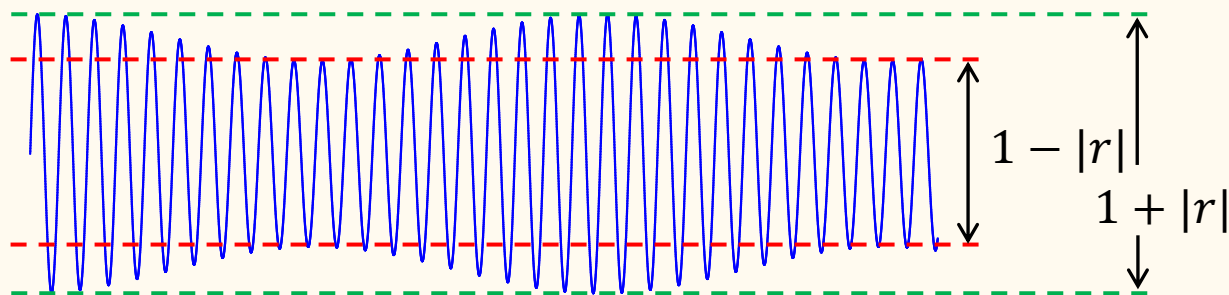
- $Z_1 = Z_0$: no reflection, *i.e.*, impedance matching
- $Z_1 = +\infty$ (open circuit end) : $r = 1$, *i.e.*, free end
- $Z_1 = 0$ (short circuit end) : $r = -1$, *i.e.*, fixed end

Connection and termination

Finite reflection \rightarrow Standing wave

Voltage-Standing Wave Ratio (VSWR):

$$\frac{1 + |r|}{1 - |r|}$$



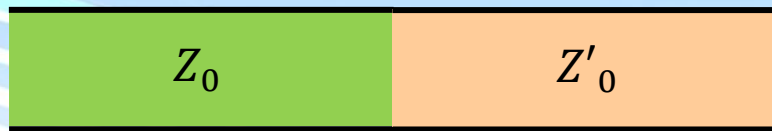
$$\left. \begin{aligned} \text{At } x = -l \quad V &= V_{+0} \exp(\kappa l) + V_{-0} \exp(-\kappa l) = [J_{+0} \exp(\kappa l) - J_{-0} \exp(-\kappa l)] Z_0 \\ J &= J_{+0} \exp(\kappa l) + J_{-0} \exp(-\kappa l) \end{aligned} \right\}$$

Then at $x = -l$ (at power source), the right hand side can be represented by

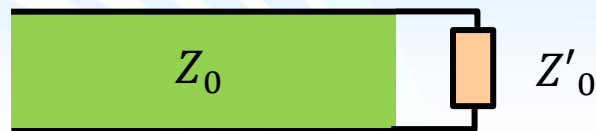
$$Z_l = \frac{V}{J} = \frac{J_{+0} e^{\kappa l} - J_{-0} e^{-\kappa l}}{J_{+0} e^{\kappa l} + J_{-0} e^{-\kappa l}} Z_0$$

Reflection coefficient:
$$r_l = \frac{V_-}{V_+} = \frac{V_{0-} \exp(-\kappa l)}{V_{0+} \exp(\kappa l)} = r \exp(-2\kappa l)$$

Connection and termination



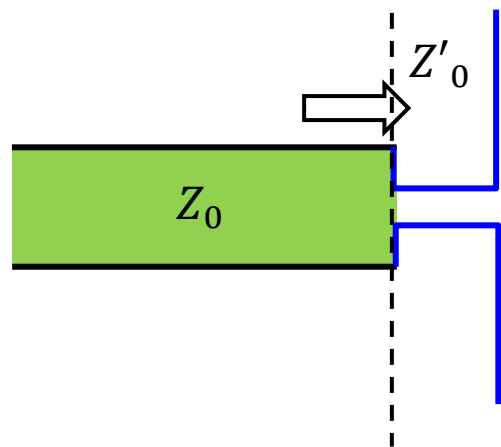
Transmission line connection.
Characteristic impedance Z_0, Z'_0



At the connection point, only the local relation between V and J affects the reflection coefficient.

The local impedance from the left hand side is Z_0' .

$$r = \frac{Z'_0 - Z_0}{Z'_0 + Z_0}$$



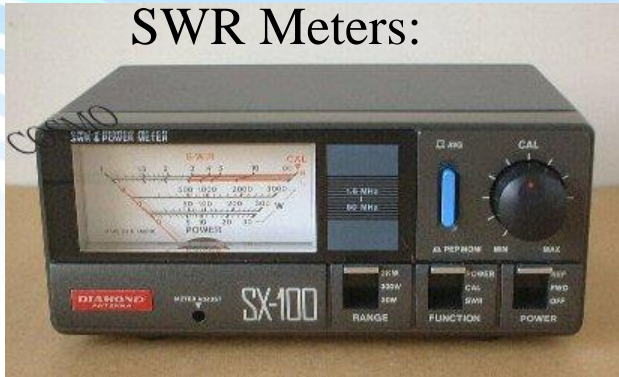
antenna

$$Z_0^V = 120\pi \approx 377 \Omega$$

Z'_0 : input impedance of antenna

SWR measurement

SWR Meters:



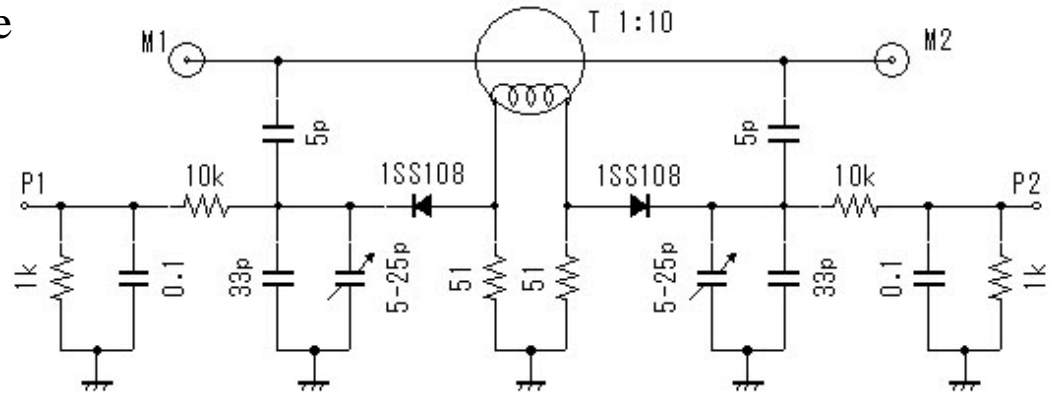
desktop types



cross-meter



handy type



directional coupler

5.2.3 Smith chart, immittance chart

End impedance Z_1 : Normalized end impedance $Z_n \equiv Z_1/Z_0$

$$Z_n = x + iy, \quad r = u + iw \quad (x, y, u, w \in \mathbb{R})$$

$$u + iw = r = \frac{Z_n - 1}{Z_n + 1} = \frac{(x - 1) + iy}{(x + 1) + iy} \quad \left. \begin{array}{l} \text{real:} \quad x - 1 = (x + 1)u - yw \\ \text{imaginary:} \quad y = yu + w(x + 1) \end{array} \right\}$$

y : erase
 x : constant

$$\left(u - \frac{x}{x + 1}\right)^2 + w^2 = \frac{1}{(x + 1)^2}$$

constant reactance circle

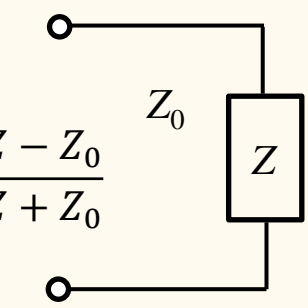
x : erase
 y : constant

$$(u - 1)^2 + \left(w - \frac{1}{y}\right)^2 = \frac{1}{y^2}$$

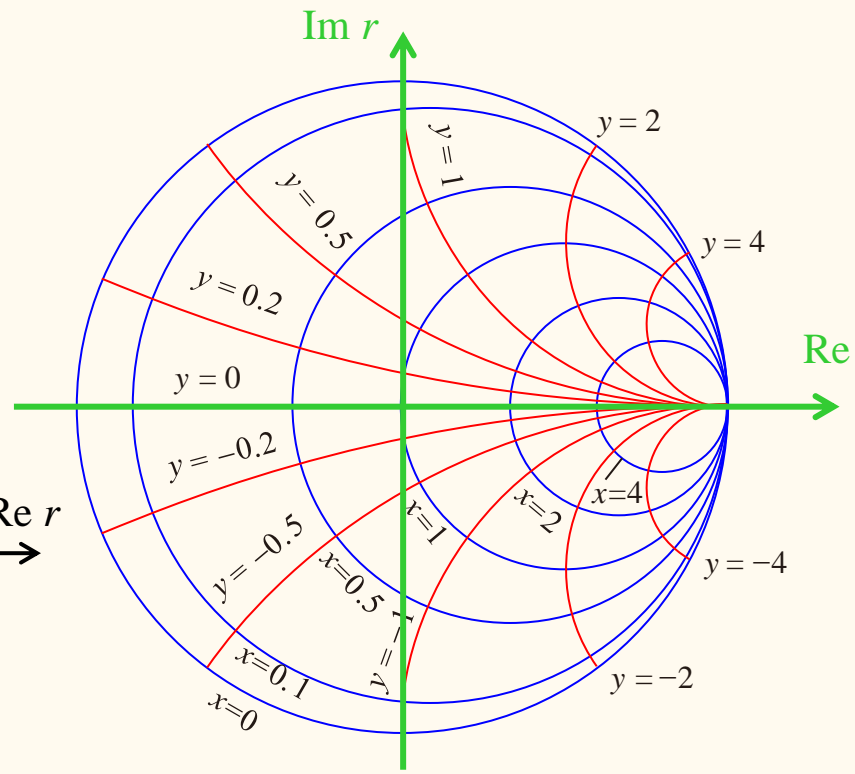
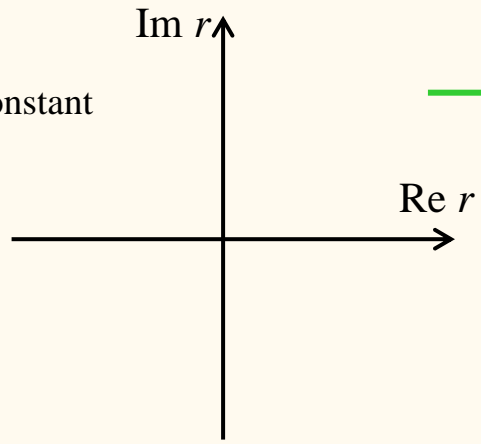
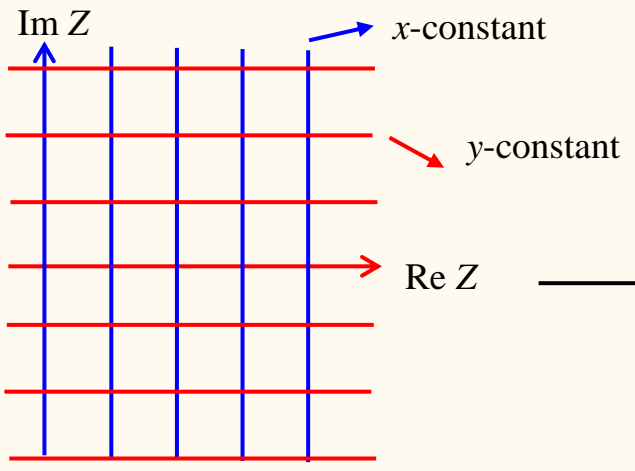
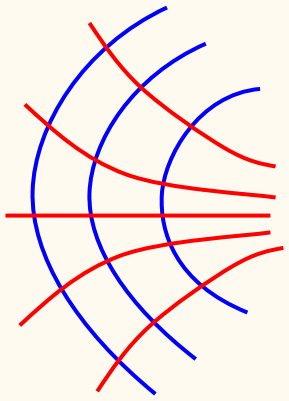
constant reactance circle

5.2.3 Smith chart, immittance chart

r : reflection coefficient



$$r = \frac{V_-}{V_+} = \frac{Z - Z_0}{Z + Z_0}$$



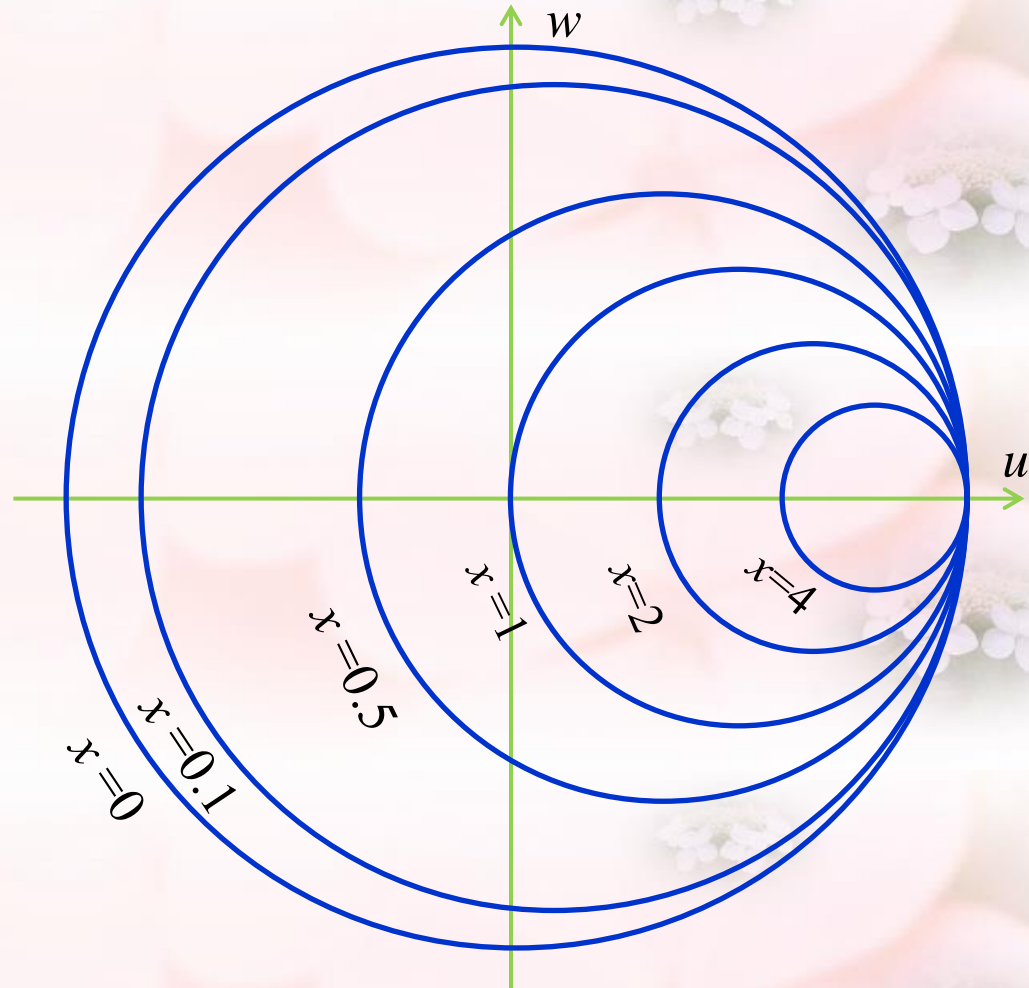
Circles with constant x

$$r = u + iw$$

$$|r| \leq 1$$

$$\left(u - \frac{x}{x+1}\right)^2 + w^2 = \frac{1}{(x+1)^2}$$

Common point: $(u, w) = (1, 0)$



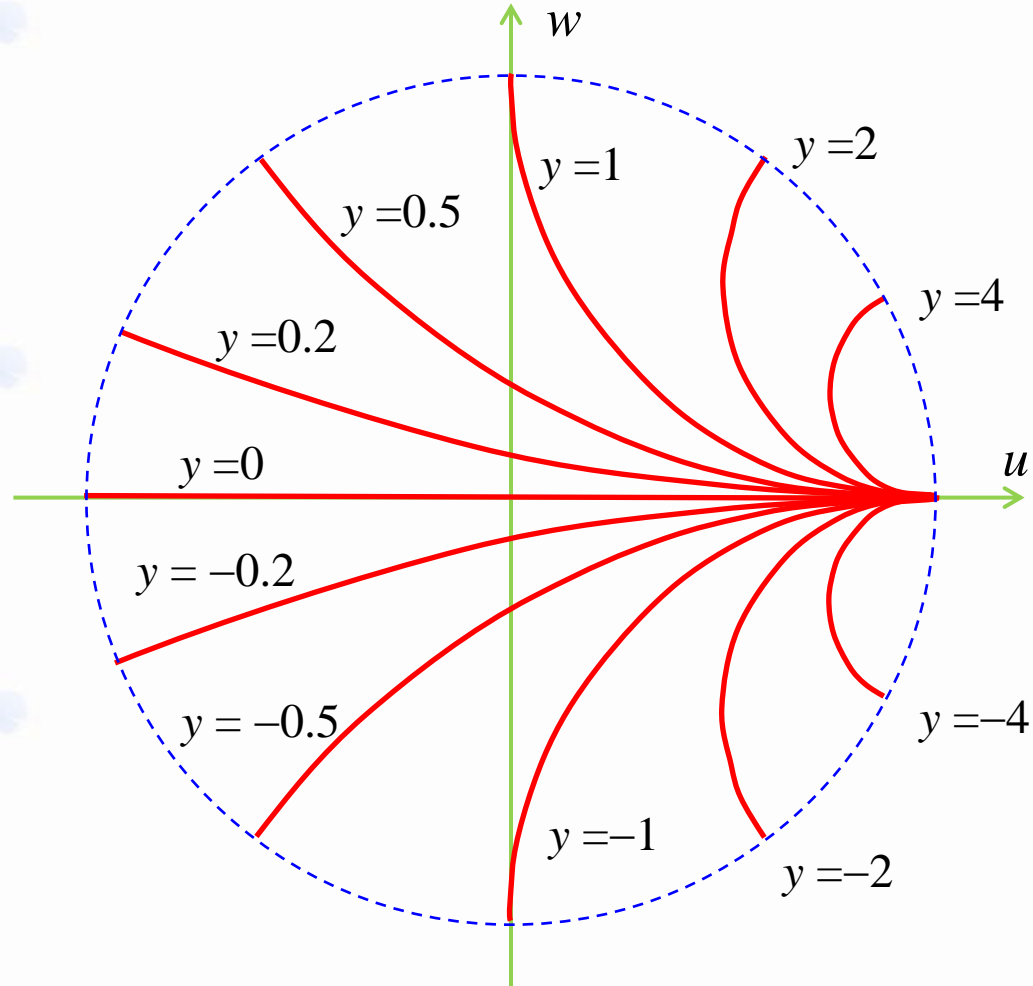
Circles with constant y

$$r = u + iw$$

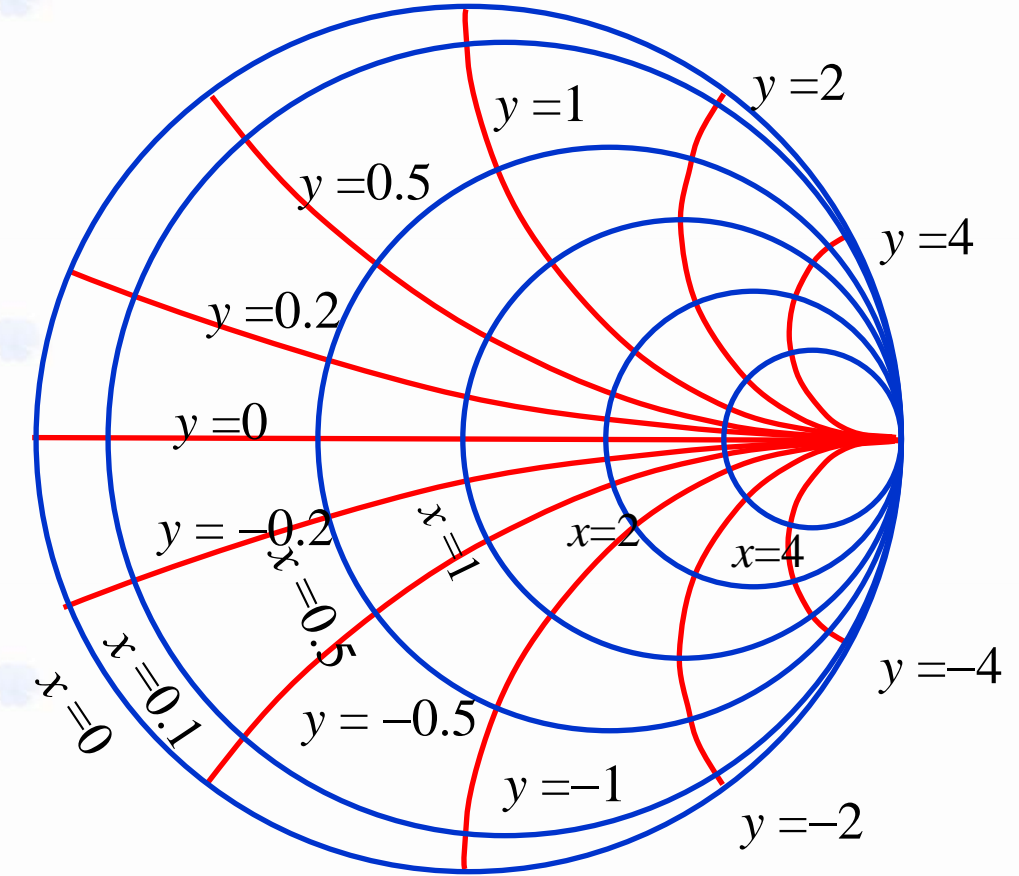
$$|r| \leq 1$$

$$(u - 1)^2 + \left(w - \frac{1}{y}\right)^2 = \frac{1}{y^2}$$

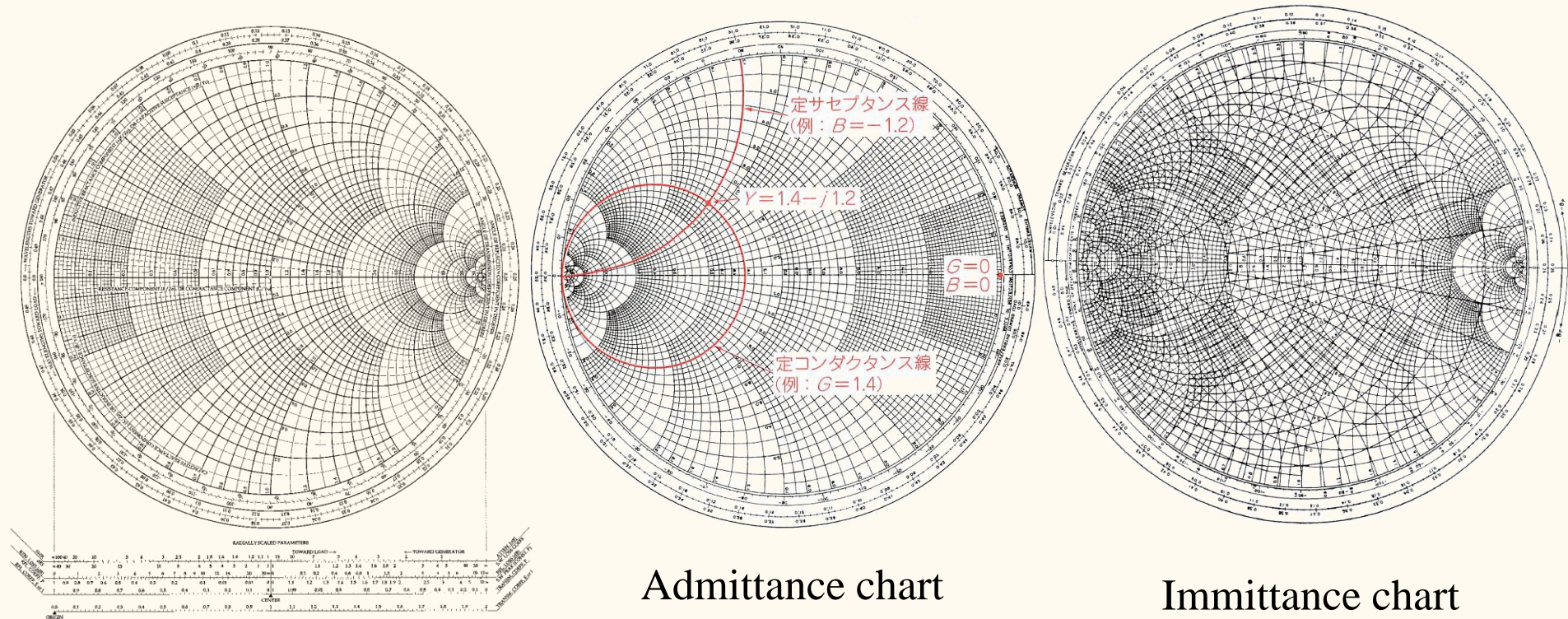
Common point: $(u, w) = (1, 0)$



Smith chart



Smith chart, immittance chart



Admittance chart

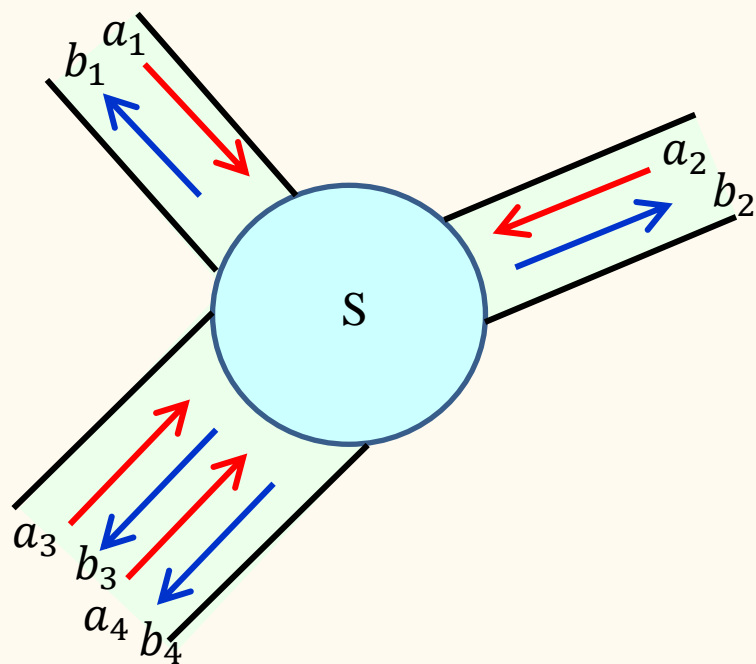
Immittance chart

5.3 Scattering (S) matrix (S parameters)

How to treat multipoint (crossing point) in transmission lines systematically?

Transmission lines: wave propagating modes \rightarrow Channels

Take $|a_i|^2$, $|b_i|^2$ to be powers (energy flow).



$$\begin{array}{c} \text{output} \\ \begin{pmatrix} b_1 \\ \vdots \\ b_i \\ \vdots \\ b_n \end{pmatrix} \end{array} = \begin{array}{c} \text{S-matrix} \\ \begin{pmatrix} S_{11} & \cdots & S_{1i} & \cdots & S_{1n} \\ \vdots & \ddots & \vdots & & \vdots \\ S_{i1} & & S_{ii} & & S_{in} \\ \vdots & & \vdots & \ddots & \vdots \\ S_{n1} & \cdots & S_{ni} & \cdots & S_{nn} \end{pmatrix} \end{array} \begin{array}{c} \text{input} \\ \begin{pmatrix} a_1 \\ \vdots \\ a_i \\ \vdots \\ a_n \end{pmatrix} \end{array}$$

$$\mathbf{b} = \mathbf{S}\mathbf{a}$$

S-matrix (S parameters)

S-matrix symmetries

Reciprocity $S_{ij} = S_{ji}$

(In case no dissipation, no amplification)

Unitarity $\sum_j S_{ji} S_{jk}^* = \delta_{ik}$

Propagation
with no dissipation

$$\left\{ \begin{array}{l} a_n = \frac{V_{n+}}{\sqrt{Z_{0n}}} = J_{n+} \sqrt{Z_{0n}}, \\ b_n = \frac{V_{n-}}{\sqrt{Z_{0n}}} = J_{n-} \sqrt{Z_{0n}} \end{array} \right.$$

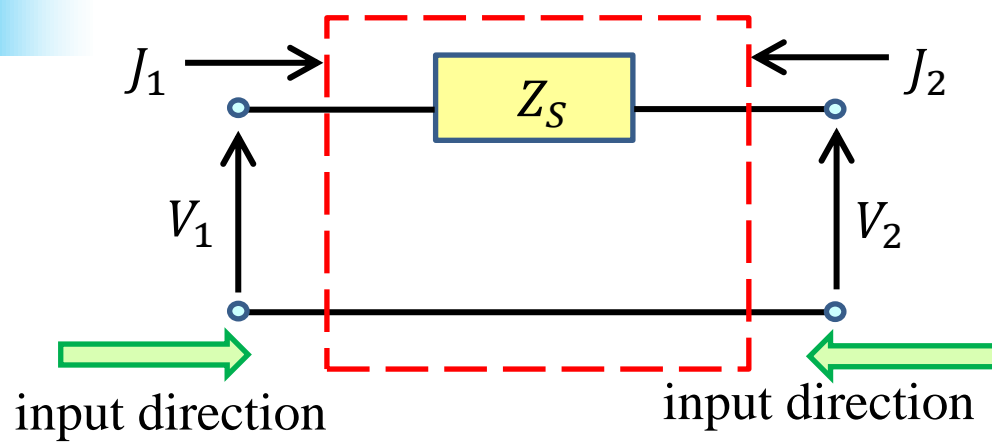
Incident power wave
Reflected (transmitted)
power wave

$$|a_n|^2 = \frac{|V_{n+}|^2}{Z_{0n}} = |J_{n+}|^2 Z_{0n}$$

S matrix (S parameters)

Simplest example: series impedance Z_S

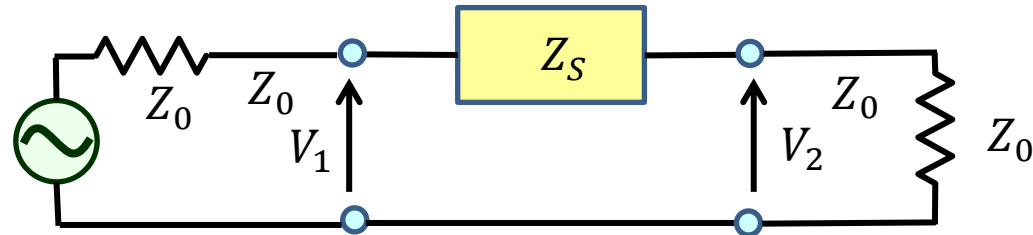
Take voltage as the “flow” quantity.
(assume common characteristic impedance)



$$\begin{pmatrix} b_1 \\ b_2 \end{pmatrix} = \begin{pmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{pmatrix} \begin{pmatrix} a_1 \\ a_2 \end{pmatrix} \quad \begin{pmatrix} V_{1-} \\ V_{2-} \end{pmatrix} = \begin{pmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{pmatrix} \begin{pmatrix} V_{1+} \\ V_{2+} \end{pmatrix}$$

Measurement (calculation) of the S-matrix in the case the above is placed in transmission line with characteristic impedance Z_0 .

Consider the case that the ends of the line is terminated with Z_0 and the source is connected at the left end.



Simple example of S-matrix

Terminate 2 with $Z_0 \rightarrow a_2 = 0$ (no reflection, no wave source at the right end)

$$S_{11} = \frac{V_{1-}}{V_{1+}} = \frac{V_1 - Z_0 J_1}{V_1 + Z_0 J_1} = \frac{Z_1 - Z_0}{Z_1 + Z_0} = \frac{(Z_S + Z_0) - Z_0}{(Z_S + Z_0) + Z_0} = \frac{Z_S}{Z_S + 2Z_0}$$

$$S_{21} = \frac{V_{2-}}{V_{1+}} = \frac{V_2 - Z_0 J_2}{V_1 + Z_0 J_1} = \frac{Z_0 J_1 + Z_0 J_1}{(Z_S + Z_0) J_1 + Z_0 J_1} = \frac{2Z_0}{Z_S + 2Z_0} \quad (J_2 = -J_1)$$

From symmetry of S-matrix: $S_{22} = S_{11} = \frac{Z_S}{Z_S + 2Z_0}$, $S_{12} = S_{21} = \frac{2Z_0}{Z_S + 2Z_0}$

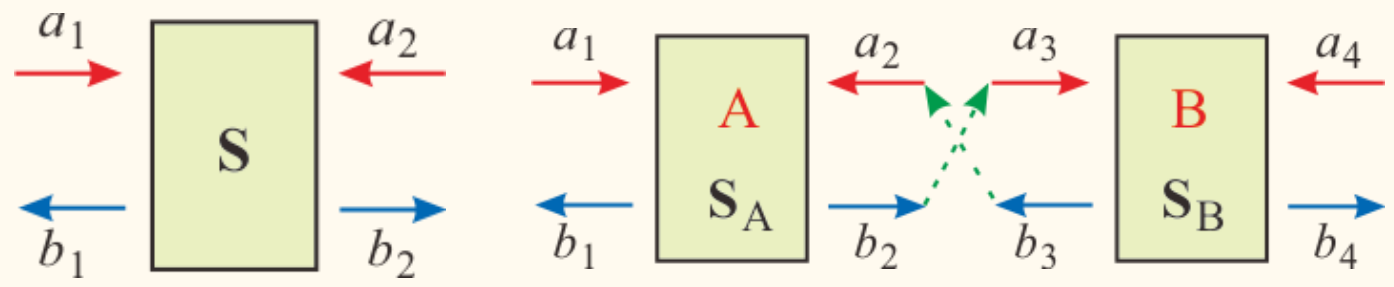
When the impedance matrix $Z = \{Z_{ij}\}$ is given, the S-matrix is obtained as

$$S = \frac{1}{\det Z} \begin{pmatrix} (Z_{11} - Z_0)(Z_{22} + Z_0) - Z_{12}Z_{21} & 2Z_0Z_{12} \\ 2Z_0Z_{21} & (Z_{11} - Z_0)(Z_{22} + Z_0) - Z_{12}Z_{21} \end{pmatrix}$$

Cascade connection of S-matrices

$$\begin{pmatrix} b_1 \\ b_2 \end{pmatrix} = \mathbf{S} \begin{pmatrix} a_1 \\ a_2 \end{pmatrix} = \begin{pmatrix} r_L & t_R \\ t_L & r_R \end{pmatrix} \begin{pmatrix} a_1 \\ a_2 \end{pmatrix} \quad r_{L,R}, t_{L,R}: \text{complex reflection, transmission coefficients satisfying}$$

$$T_{L,R} = |t_{L,r}|^2 = 1 - R_{L,R} = 1 - |r_{L,R}|^2$$

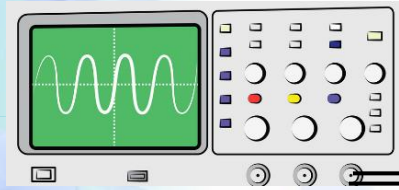


$$\mathbf{S}_{AB} = \begin{pmatrix} r_L^{AB} & t_R^{AB} \\ t_L^{AB} & r_R^{AB} \end{pmatrix} = \begin{pmatrix} r_L^A + t_R^A r_L^B (I - r_R^A r_L^B)^{-1} t_L^A & t_R^A (I - r_L^B r_R^A)^{-1} t_R^B \\ t_L^B (I - r_R^A r_L^B)^{-1} t_L^A & r_R^B + t_L^B (I - r_R^A r_L^B)^{-1} r_R^A t_R^B \end{pmatrix}$$

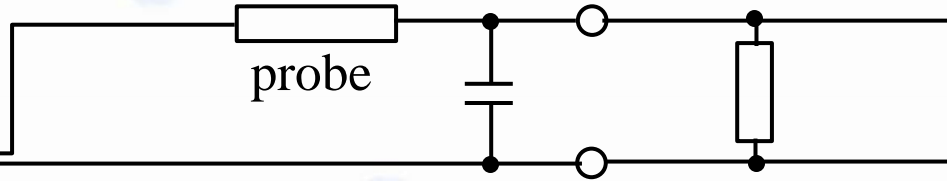
$$(I - r_R^A r_L^B)^{-1} = I + r_R^A r_L^B + (r_R^A r_L^B)^2 + \dots$$

Why we need S-matrix (S-parameters) for high frequency lines?

Difficulty in measurement of voltage at high frequencies.



oscilloscope



1. Cannot ignore distributed capacitance
2. Probe line should also be treated as a transmission line

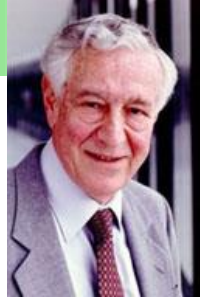
Vector network
analyzer



On the other hand, S-parameters can be obtained from power measurements.

S-parameters give enough information for designing high frequency circuits.

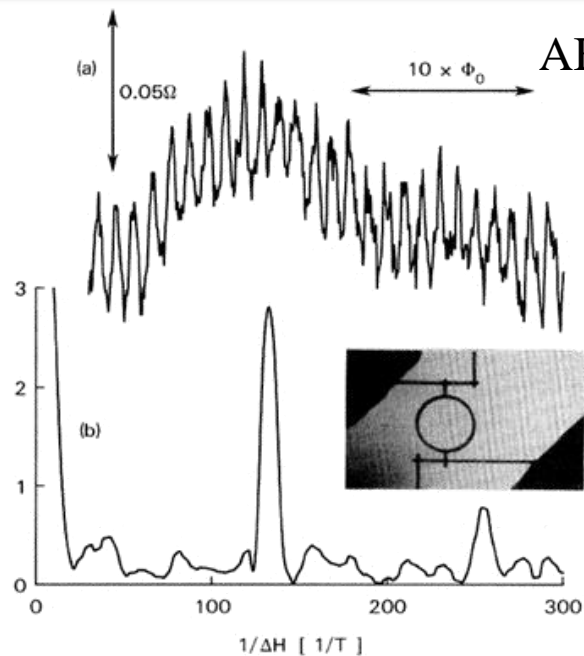
Application of S-matrix to quantum transport



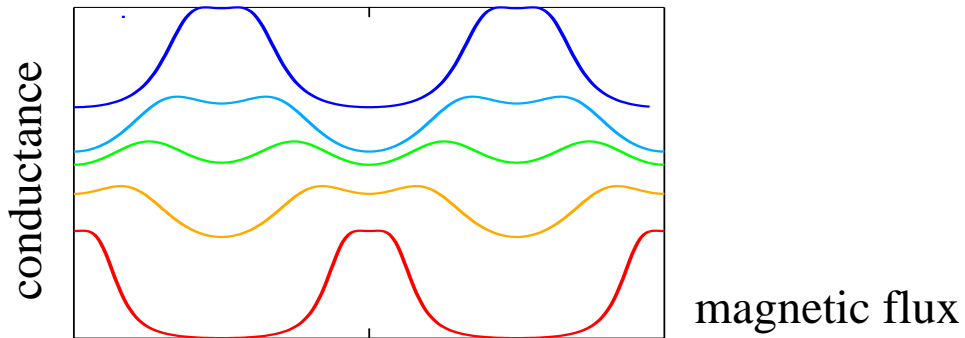
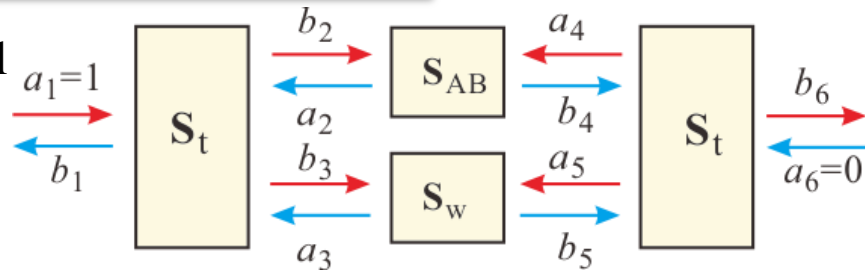
Rolf Landauer

Electron (quantum mechanical) waves also have propagating modes in solids.
→ Conduction channel

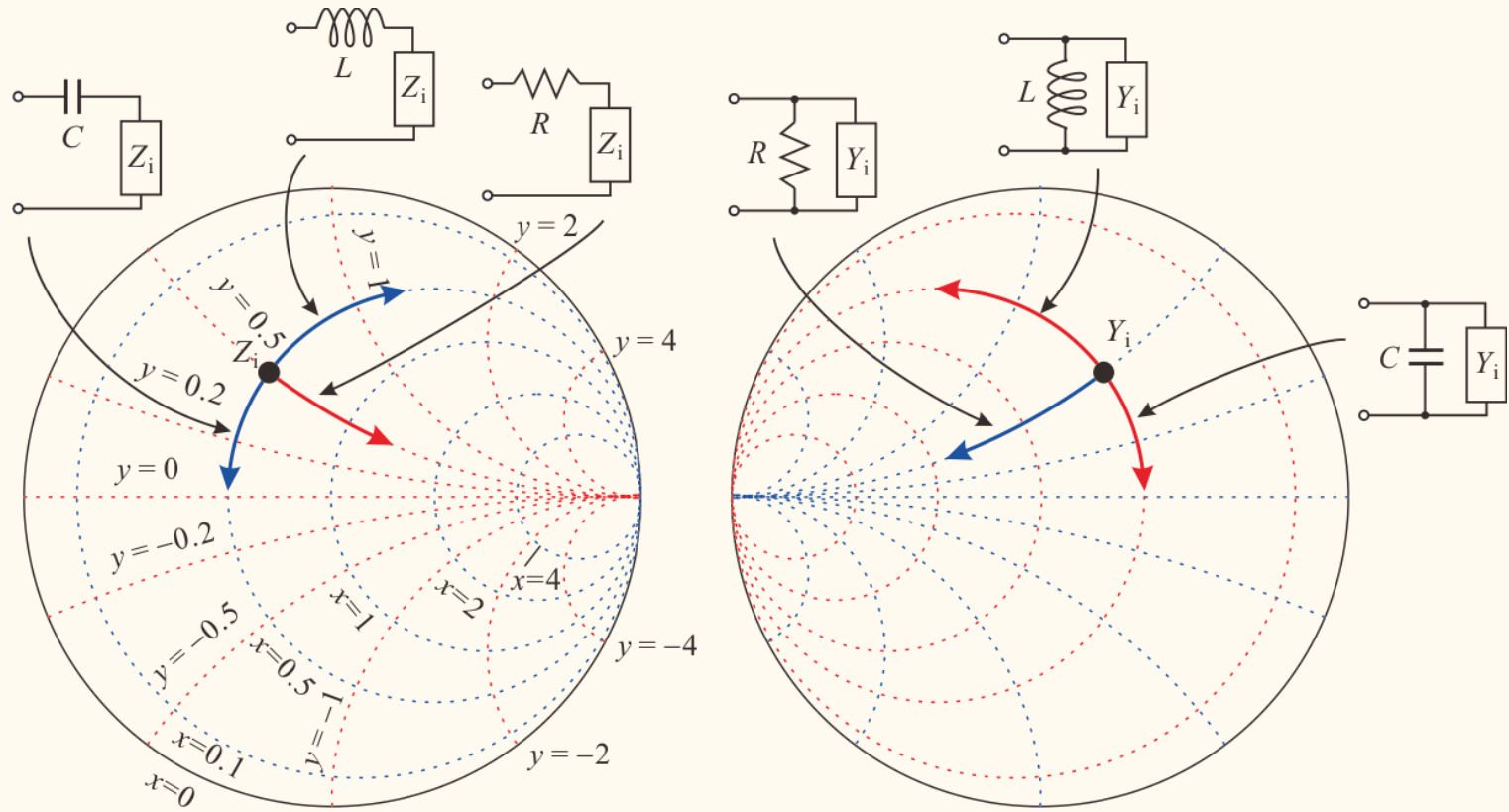
Landauer equation: the conductance of a single perfect quantum channel is $\frac{e^2}{h}$



AB ring S-matrix model



Practical impedance matching with Smith chart



Impedance matching designer

<http://home.sandiego.edu/~ekim/e194rfs01/jwmatcher/matcher2.html>

Impedance Matching Network Designer

(Now with 16 networks!)

Source Resistance: Source Reactance:

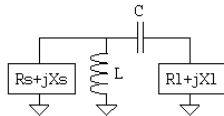
Load Resistance: Load Reactance:

Desired Q: Frequency:

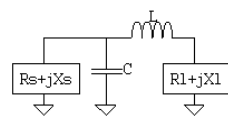
Please send comments and questions to [John Wetherell](mailto:wetherel@eecs.berkeley.edu) at wetherel@eecs.berkeley.edu

HIGHPASS HI-LOW MATCHING NETWORK

LOWPASS HI-LOW MATCHING NETWORK



L Value: nH



L Value: nH

http://leleivre.com/rf_lcmatch.html

LE LEIVRE.COM

Home

RF Tools

Software

Notes

Misc



RF Tools

- [ADC alias calculator](#)
- [ADC spurious calculator](#)
- [Attenuator calculator PI](#)
- [Attenuator calculator T](#)
- [Bramham matching transformer](#)
- [Butterworth filter designer](#)
- [Cascaded Noise Figure calculator](#)
- [Chebyshev filter designer](#)
- [C-Coupled Resonator designer](#)
- [Coax Impedance calculator](#)
- [Chip Resistor De-rating calculator](#)
- [dBm/linear power converter](#)

LC Impedance matching network designer

Enter the input and output impedances to be matched and the centre frequency. Values for L and C will be calculated for the four topologies shown.

Frequency

MHz

Zs (Rs+jXs)

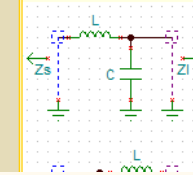
Ω

Zl (Rl+jXl)

Ω

$j\Omega$

$j\Omega$



L

C

An example FET power matching

NEC

DATA SHEET

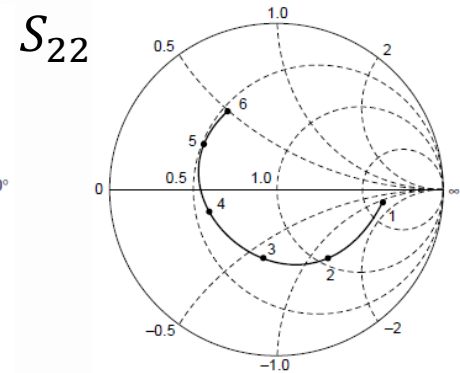
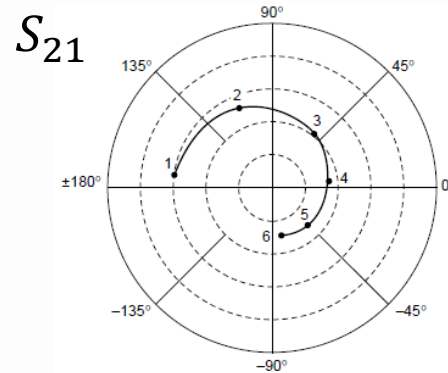
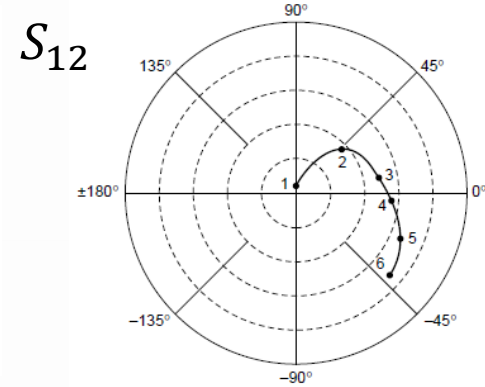
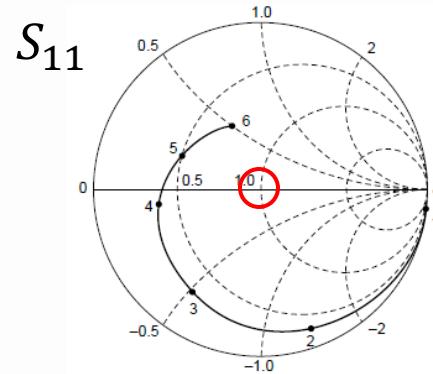
GaAs MES FET
NE76084

C to Ku BAND LOW NOISE AMPLIFIER
N-CHANNEL GaAs MES FET

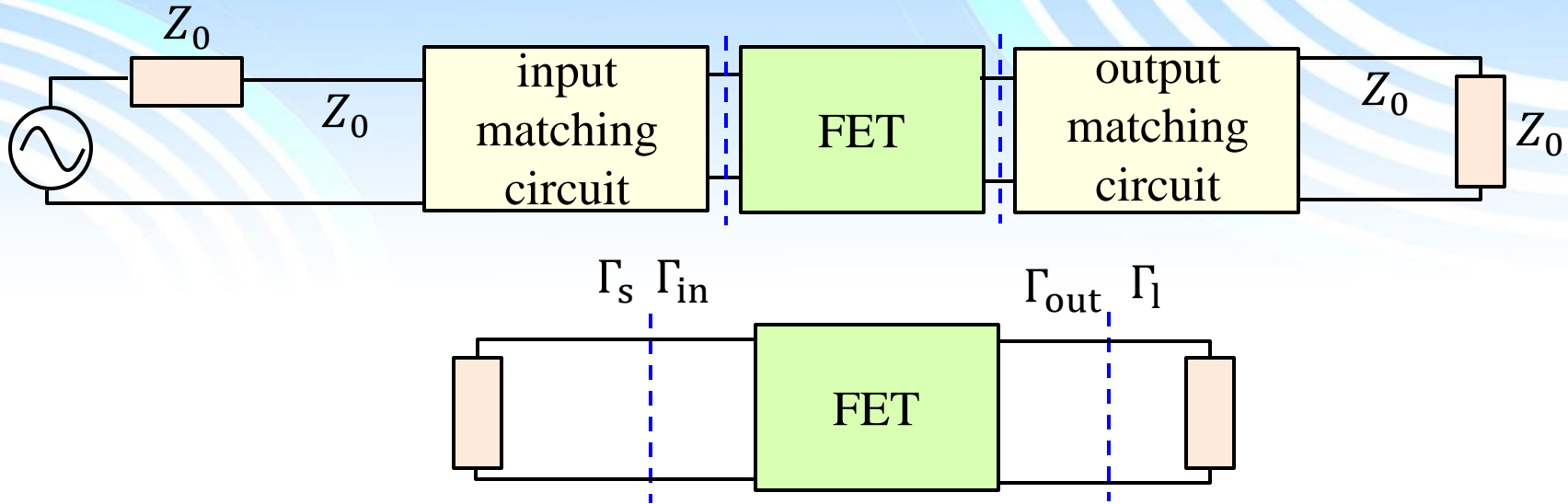


C band: 4 – 8 GHz
X band: 8 – 12 GHz
Ku band: 12 – 18 GHz

The datasheet tells that we need impedance matching circuits with transmission lines.



S parameter representation and matching circuits



$\Gamma_{s,l,in,out}$: reflection coefficients.

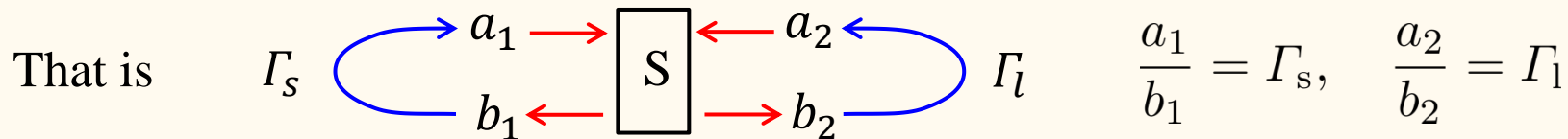
$$\begin{pmatrix} b_1 \\ b_2 \end{pmatrix} = \begin{pmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{pmatrix} \begin{pmatrix} a_1 \\ a_2 \end{pmatrix}$$

FET S-matrix

The situation can be seen as:

Source with reflection coefficient Γ_s , load with reflection coefficient Γ_l are connected.

Power matching with S-parameters



Then the total coefficients are $\Gamma_{\text{in}} = S_{11} + \frac{S_{12}S_{21}\Gamma_l}{1 - S_{22}\Gamma_l}$, $\Gamma_{\text{out}} = S_{22} + \frac{S_{12}S_{21}\Gamma_s}{1 - S_{22}\Gamma_s}$

The power matching conditions are

$$\Gamma_l = \Gamma_{\text{out}}^*, \quad \Gamma_s = \Gamma_{\text{in}}^*$$

The quadratic equation gives

$$\Gamma_s = \frac{B_1 \pm \sqrt{B_1^2 - 4|M|^2}}{2M}, \quad \Gamma_l = \frac{B_2 \pm \sqrt{B_2^2 - 4|N|^2}}{2N}$$

$$B_1 = 1 + |S_{11}|^2 - |S_{22}|^2 - |\det S|^2, \quad B_2 = 1 - |S_{11}|^2 + |S_{22}|^2 - |\det S|^2,$$
$$N = S_{22} - S_{11}^* \det S, \quad M = S_{11} - S_{22}^* \det S$$

Then the problem is reduced to tune the passive circuits to Γ_s and Γ_l